

# DATA SHEET

## **PDTC144W series**

NPN resistor-equipped transistors;

R1 = 47 k $\Omega$ , R2 = 22 k $\Omega$

Product specification  
Supersedes data of 2002 Mar 14

2003 Apr 14

# NPN resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = 22 k $\Omega$

## PDTC144W series

### FEATURES

- Built-in bias resistors
- Simplified circuit design
- Reduction of component count
- Reduced pick and place costs.

### APPLICATIONS

- General purpose switching and amplification
- Inverter and interface circuits
- Circuit driver.

### QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V <sub>CEO</sub>	collector-emitter voltage	–	50	V
I <sub>O</sub>	output current (DC)	–	100	mA
R1	bias resistor	47	–	k $\Omega$
R2	open	22	–	k $\Omega$

### DESCRIPTION

NPN resistor-equipped transistor (see “Simplified outline, symbol and pinning” for package details).

### PRODUCT OVERVIEW

TYPE NUMBER	PACKAGE		MARKING CODE	PNP COMPLEMENT
	PHILIPS	EIAJ		
PDTC144WEF	SOT490	SC-89	34	PDTA144WEF
PDTC144WK	SOT346	SC-59	41	PDTA144WK
PDTC144WM	SOT883	SC-101	DD	–
PDTC144WS	SOT54 (TO-92)	SC-43	TC144W	PDTA144WS
PDTC144WT	SOT23	–	*20 <sup>(1)</sup>	PDTA144WT
PDTC144WU	SOT323	SC-70	*20 <sup>(1)</sup>	PDTA144WU

### Note

- \* = p: Made in Hong Kong.  
\* = t: Made in Malaysia.  
\* = W: Made in China.

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SIMPLIFIED OUTLINE, SYMBOL AND PINNING

TYPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL	PINNING	
		PIN	DESCRIPTION
PDTC124WS	<p>MAM364</p>	1 2 3	base collector emitter
PDTC144WEF PDTC144WK PDTC144WT PDTC144WU	<p>Top view</p> <p>MDB269</p>	1 2 3	base emitter collector
PDTC144WM	<p>bottom view</p> <p>MHC506</p>	1 2 3	base emitter collector

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### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	–	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	–	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	–	10	V
V <sub>i</sub>	input voltage				
	positive		–	+40	V
	negative		–	–10	V
I <sub>O</sub>	output current (DC)		–	100	mA
I <sub>CM</sub>	peak collector current		–	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C			
	SOT54	note 1	–	500	mW
	SOT23	note 1	–	250	mW
	SOT346	note 1	–	250	mW
	SOT323	note 1	–	200	mW
	SOT490	notes 1 and 2	–	250	mW
	SOT883	notes 2 and 3	–	250	mW
T <sub>stg</sub>	storage temperature		–65	+150	°C
T <sub>j</sub>	junction temperature		–	150	°C
T <sub>amb</sub>	operating ambient temperature		–65	+150	°C

### Notes

1. Refer to standard mounting conditions.
2. Reflow soldering is the only recommended soldering method.
3. Refer to SOT883 standard mounting conditions; FR4 with 60  $\mu$ m copper strip line.

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	in free air		
	SOT54	note 1	250	K/W
	SOT23	note 1	500	K/W
	SOT346	note 1	500	K/W
	SOT323	note 1	625	K/W
	SOT490	notes 1 and 2	500	K/W
	SOT883	notes 2 and 3	500	K/W

### Notes

1. Refer to standard mounting conditions.
2. Reflow soldering is the only recommended soldering method.
3. Refer to SOT883 standard mounting conditions; FR4 with 60  $\mu$ m copper strip line.

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## CHARACTERISTICS

$T_{\text{amb}} = 25\text{ }^{\circ}\text{C}$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$I_{\text{CBO}}$	collector-base cut-off current	$V_{\text{CB}} = 50\text{ V}$ ; $I_{\text{C}} = 0$	–	–	100	nA
$I_{\text{CEO}}$	collector-emitter cut-off current	$V_{\text{CE}} = 30\text{ V}$ ; $I_{\text{B}} = 0$	–	–	1	$\mu\text{A}$
		$V_{\text{CE}} = 30\text{ V}$ ; $I_{\text{B}} = 0$ ; $T_{\text{j}} = 150\text{ }^{\circ}\text{C}$	–	–	50	$\mu\text{A}$
$I_{\text{EBO}}$	emitter-base cut-off current	$V_{\text{EB}} = 5\text{ V}$ ; $I_{\text{C}} = 0$	–	–	110	$\mu\text{A}$
$h_{\text{FE}}$	DC current gain	$V_{\text{CE}} = 5\text{ V}$ ; $I_{\text{C}} = 5\text{ mA}$	60	–	–	
$V_{\text{CEsat}}$	collector-emitter saturation voltage	$I_{\text{C}} = 10\text{ mA}$ ; $I_{\text{B}} = 0.5\text{ mA}$	–	–	150	mV
$V_{\text{i(off)}}$	input-off voltage	$I_{\text{C}} = 100\text{ }\mu\text{A}$ ; $V_{\text{CE}} = 5\text{ V}$	–	1.7	1.2	V
$V_{\text{i(on)}}$	input-on voltage	$I_{\text{C}} = 2\text{ mA}$ ; $V_{\text{CE}} = 0.3\text{ V}$	4	2.7	–	V
$R1$	input resistor		33	47	61	$\text{k}\Omega$
$\frac{R2}{R1}$	resistor ratio		0.37	0.47	0.57	
$C_{\text{c}}$	collector capacitance	$I_{\text{E}} = i_{\text{e}} = 0$ ; $V_{\text{CB}} = 10\text{ V}$ ; $f = 1\text{ MHz}$	–	–	2.5	pF

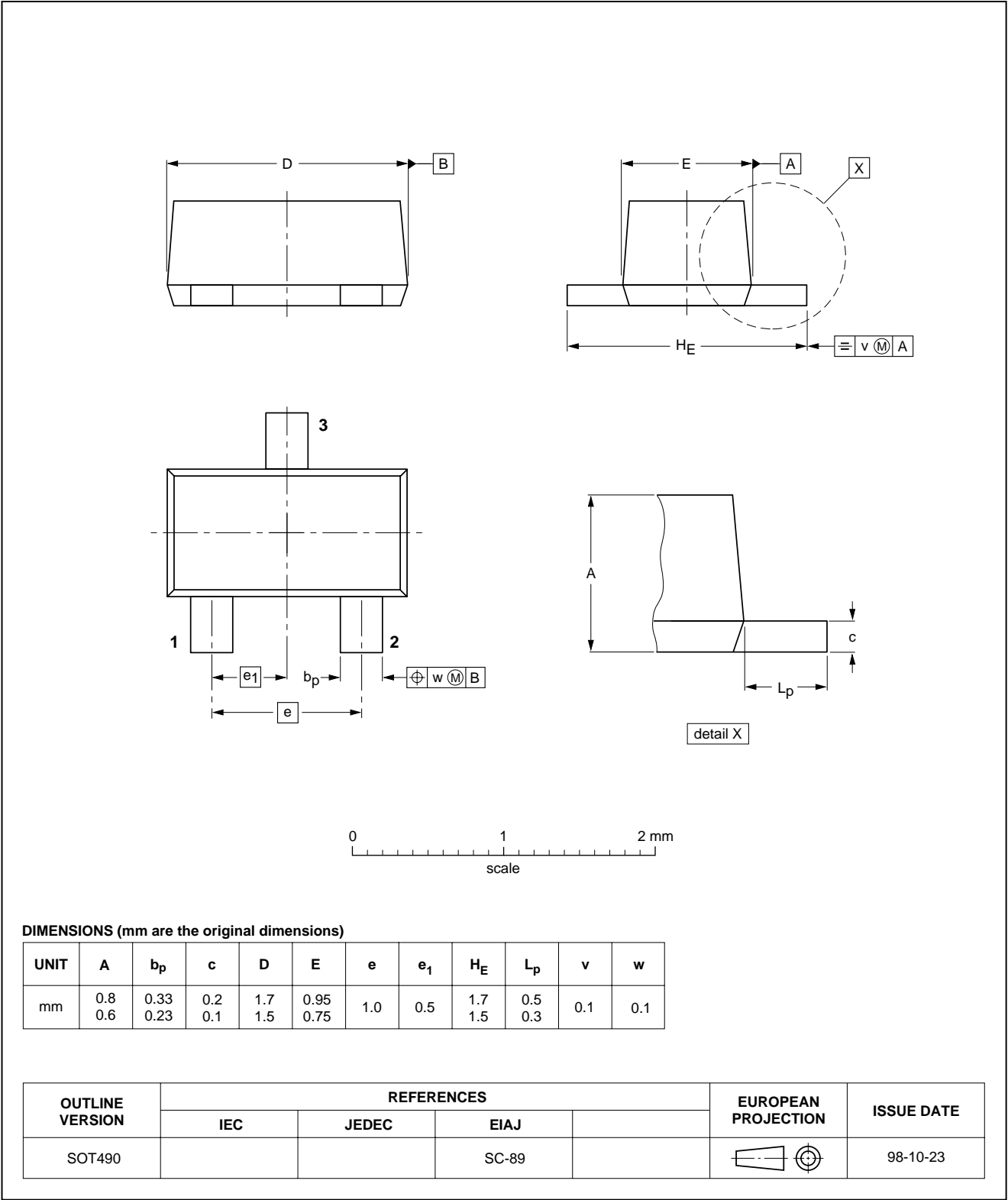
NPN resistor-equipped transistors;  
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PDTC144W series

PACKAGE OUTLINES

Plastic surface mounted package; 3 leads

SOT490

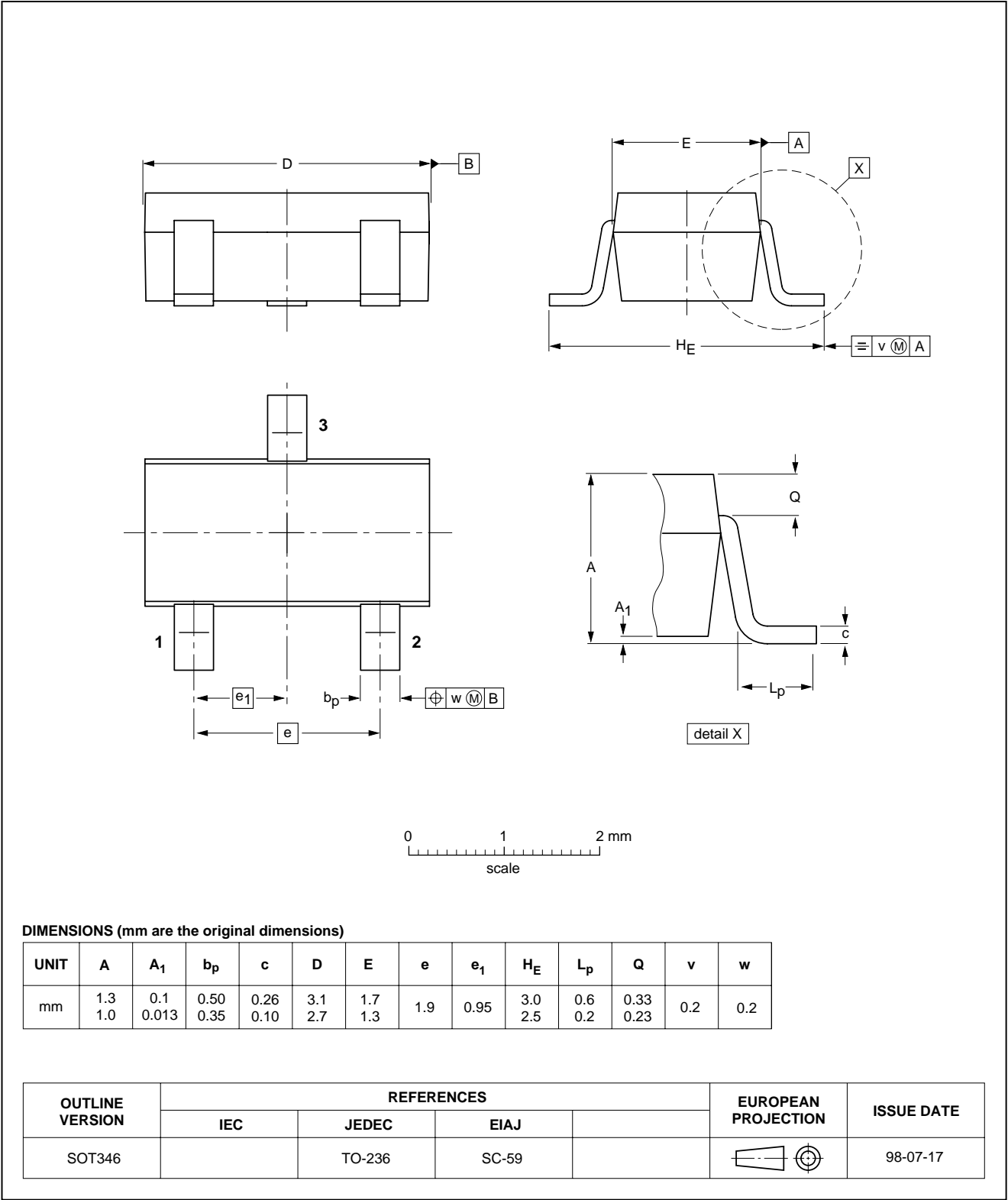


NPN resistor-equipped transistors;  
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PDTC144W series

Plastic surface mounted package; 3 leads

SOT346

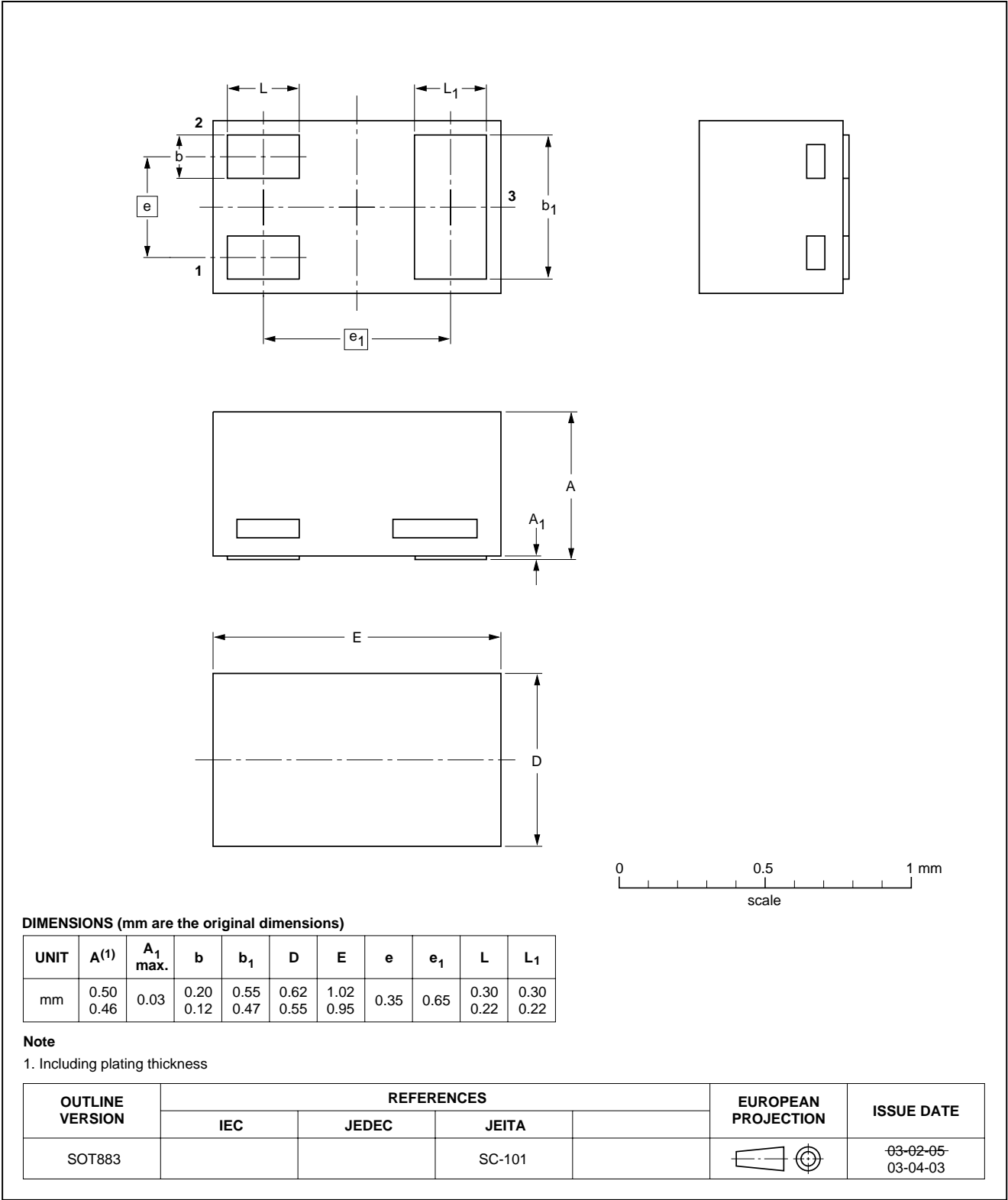


NPN resistor-equipped transistors;  
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PDTC144W series

Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm

SOT883



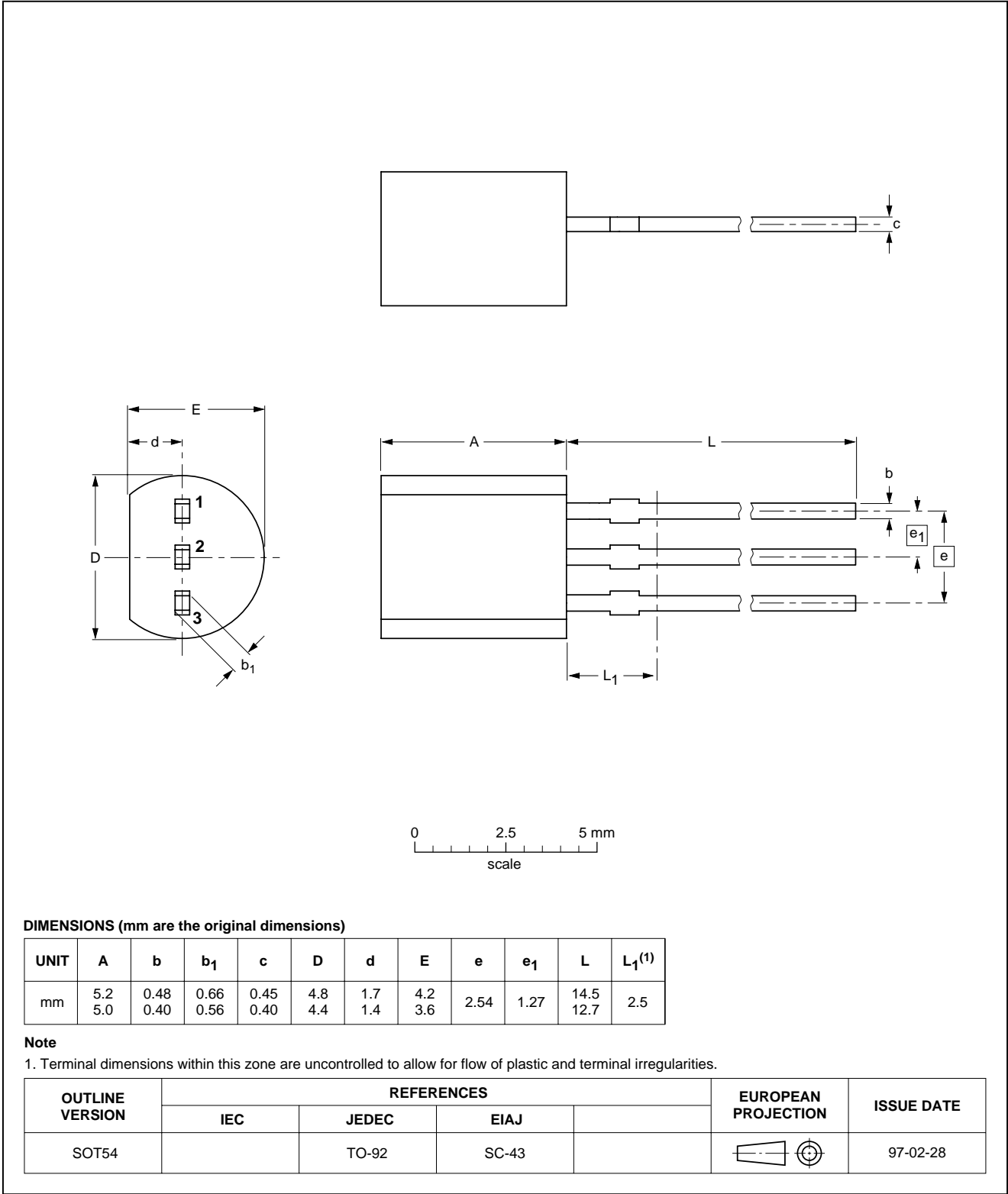


NPN resistor-equipped transistors;  
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PDTC144W series

Plastic single-ended leaded (through hole) package; 3 leads

SOT54

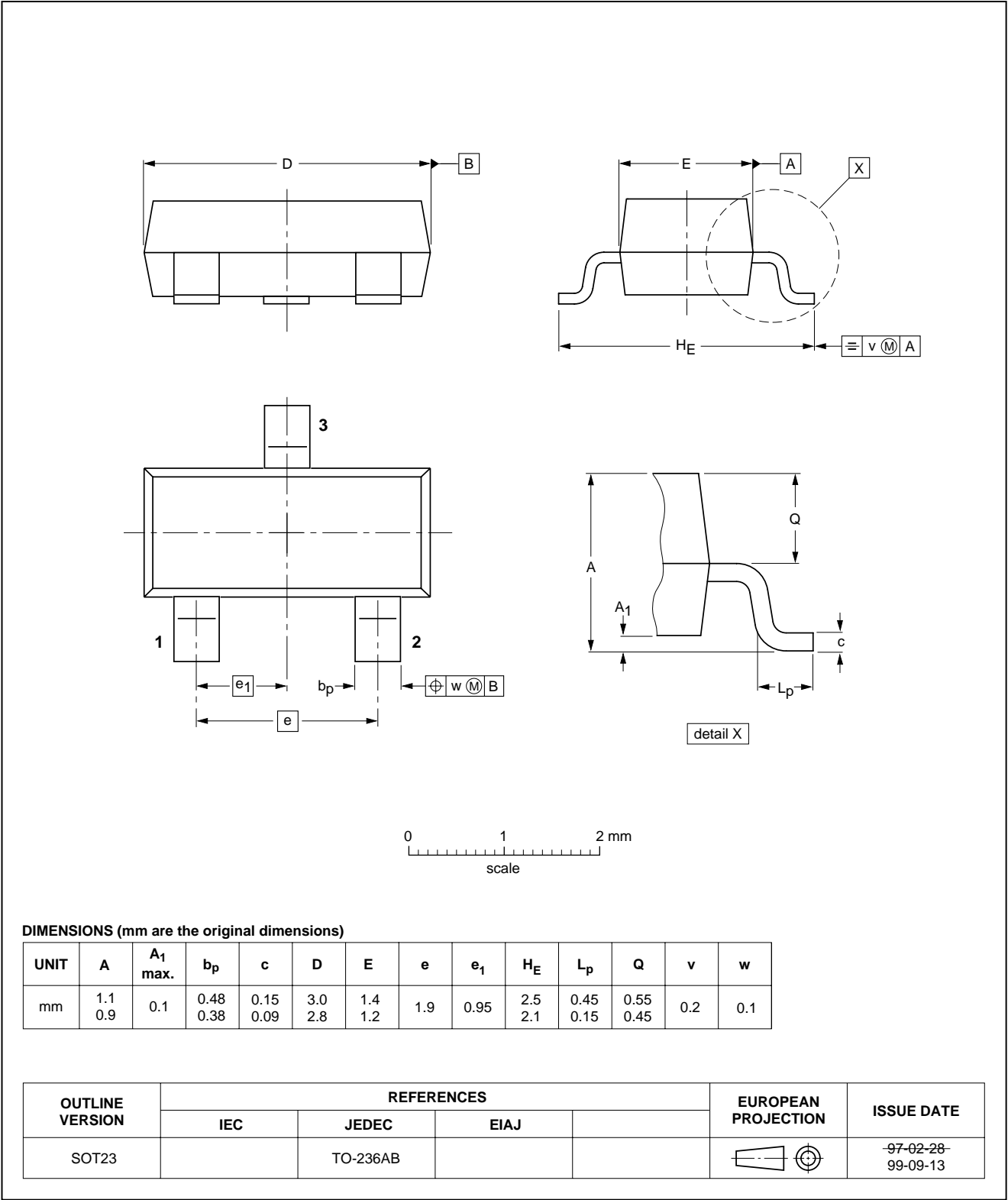


NPN resistor-equipped transistors;  
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Plastic surface mounted package; 3 leads

SOT23

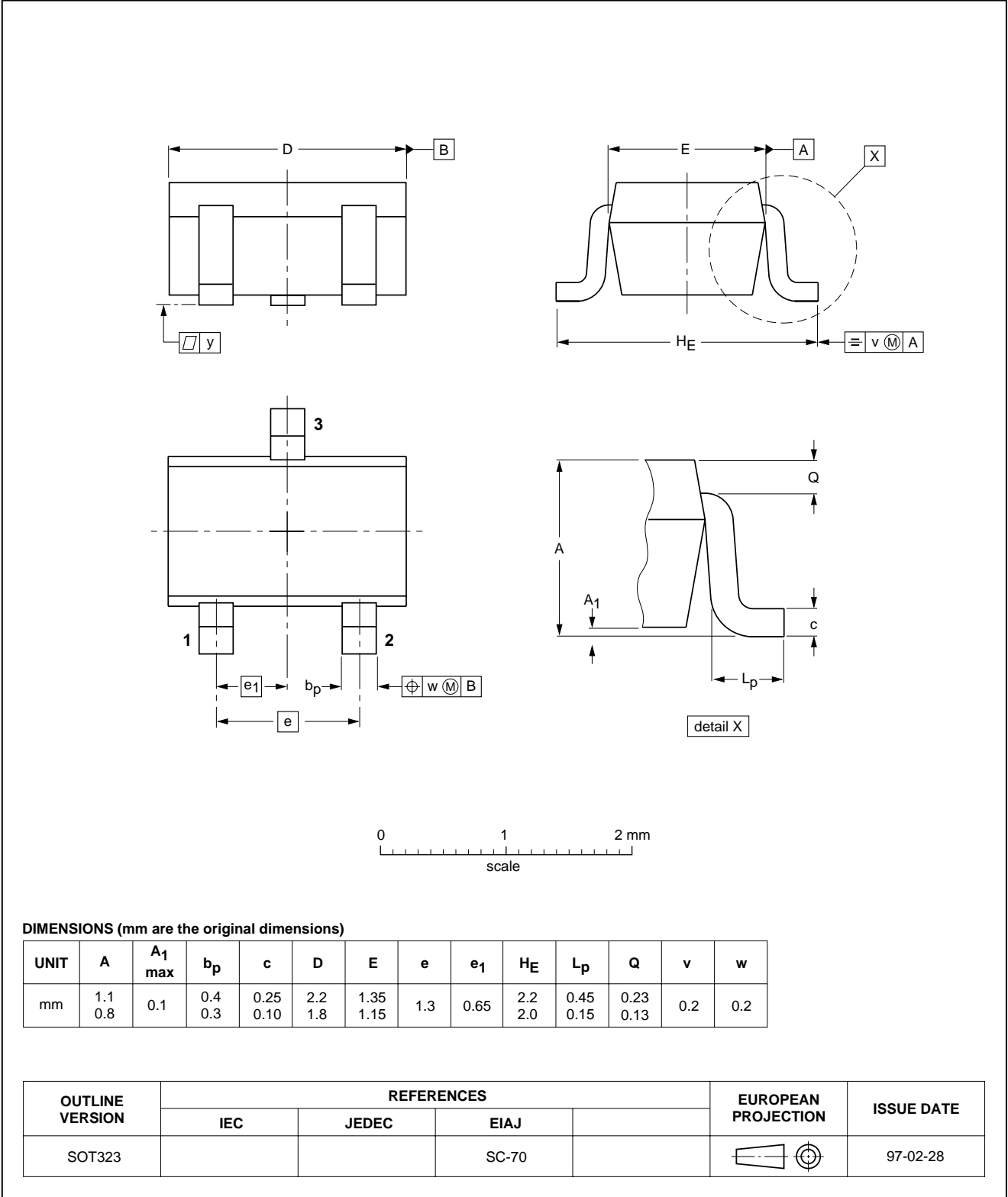


NPN resistor-equipped transistors;  
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PDTC144W series

Plastic surface mounted package; 3 leads

SOT323



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#### DATA SHEET STATUS

LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)(3)</sup>	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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#### NOTES

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#### NOTES

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## **Contact information**

For additional information please visit **<http://www.semiconductors.philips.com>**. Fax: **+31 40 27 24825**

For sales offices addresses send e-mail to: **[sales.addresses@www.semiconductors.philips.com](mailto:sales.addresses@www.semiconductors.philips.com)**.

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